



Beta-enhanced Thermionic Diamond Energy Converters (BTDC) and Nuclear Batteries Project

NASA 2014 Workshop
Houston
14th October 2014

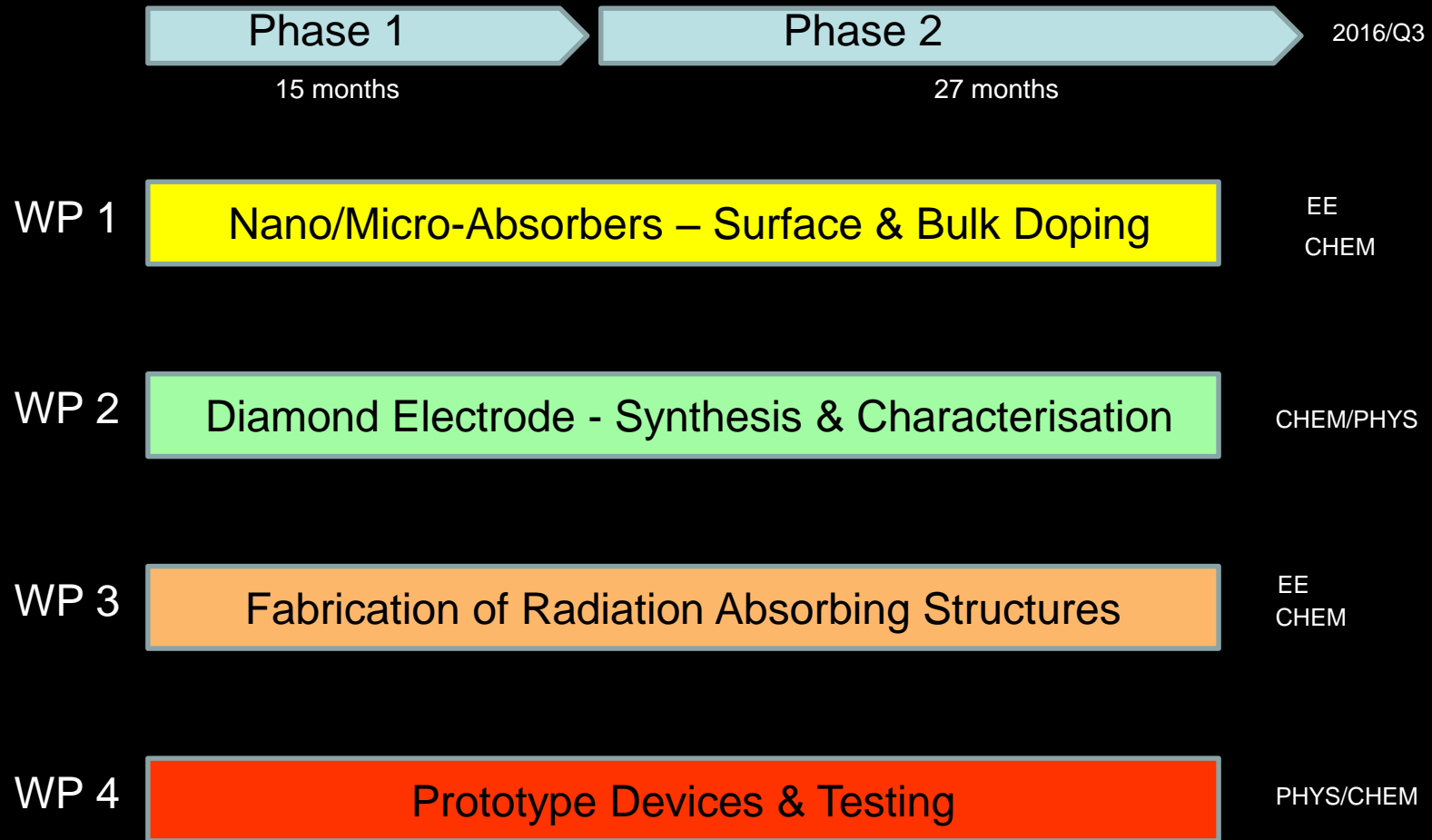
Dr. Neil A Fox
Project Principal Investigator
University of Bristol
UK

OUTLINE

- PROJECT SCOPE & OBJECTIVES
- SUPPORTING WORK
- PROJECT RESULTS

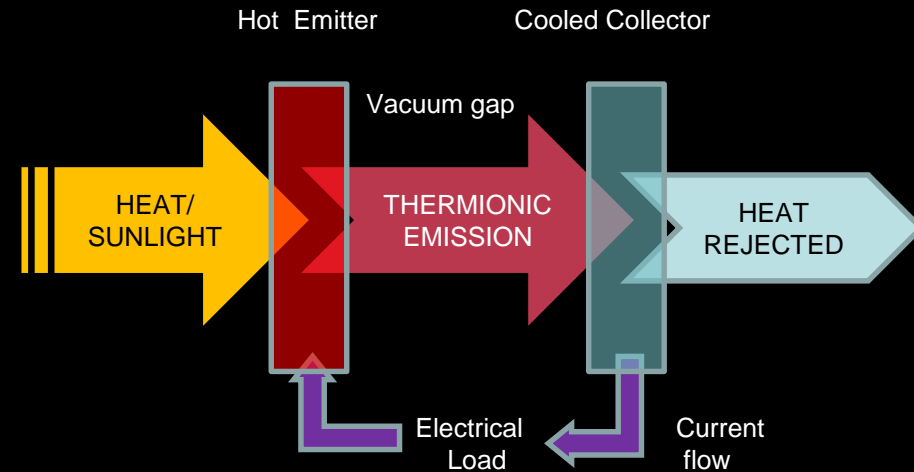


Research Programme



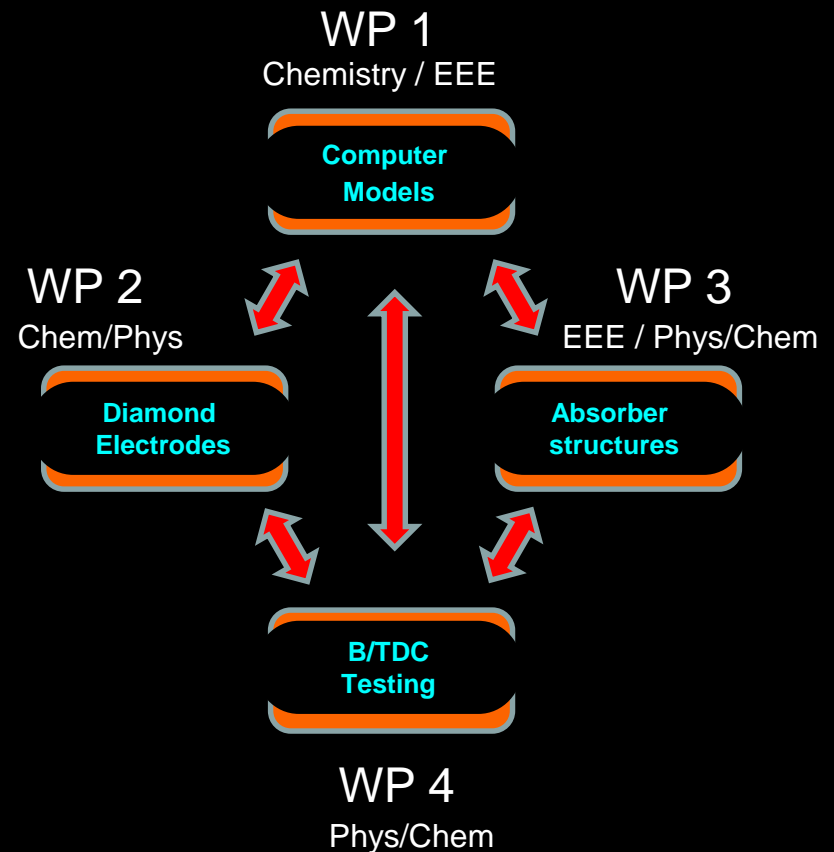
Thermionic Diamond Converter (TDC)

- Solid State Conversion of Heat / Radiation to Electrical Power
- Function of Components Parts
 - Emitter /Cathode
 - Photon absorber (input side)
 - Thermionic emitter (output side)
 - Collector /Anode
 - Electron absorber (input side)
 - Heat sink (output side)



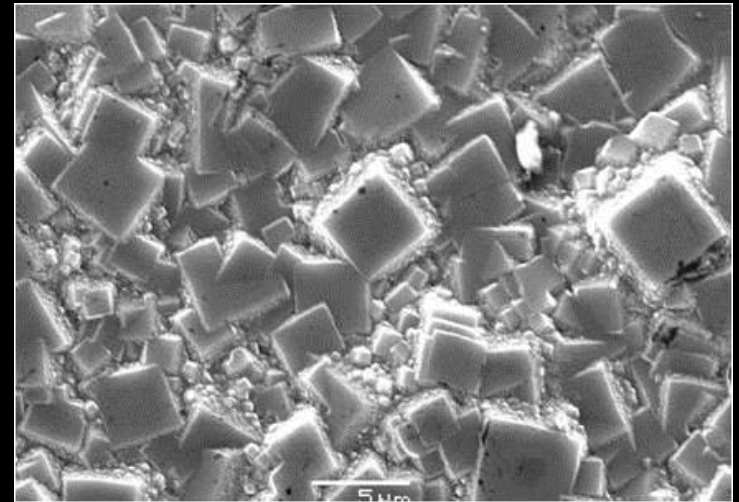
Project objectives

- High current thermionic emission from diamond
- High efficiency radiation absorbers
- Diamond solar energy converter
- Beta-enhanced thermionics
- Beta-diamond nuclear battery

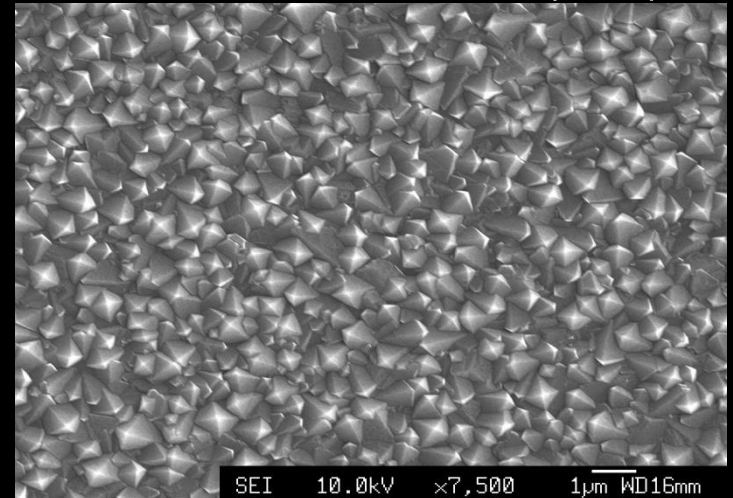


CVD Diamond

- Material Requirements for Thermionic Diamond
 - Low Work Function surfaces with Stable Negative Electron Affinity
 - High Electrical Conductivity using efficiently doped n-type layers



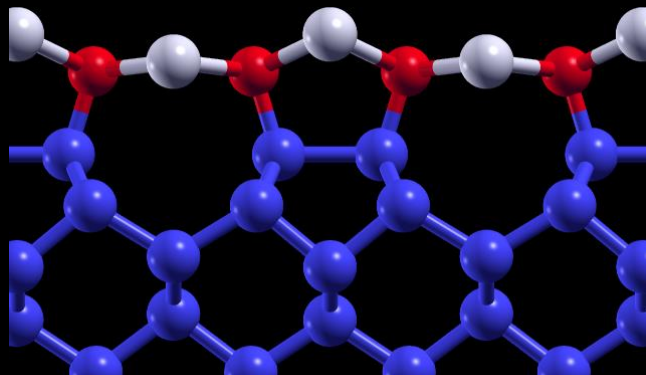
Emitter Surface - C(100)



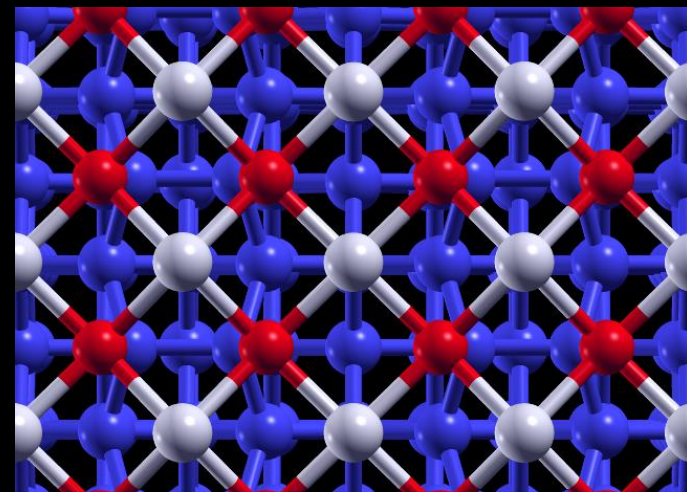
Collector surface – C(111)

🔥 Diamond Surface Studies - Modelling

- Oxygen forms stronger bonds with Li than C does. On the other hand, O-terminated surfaces have a very high PEA (high negative surface charge due to lone pairs).

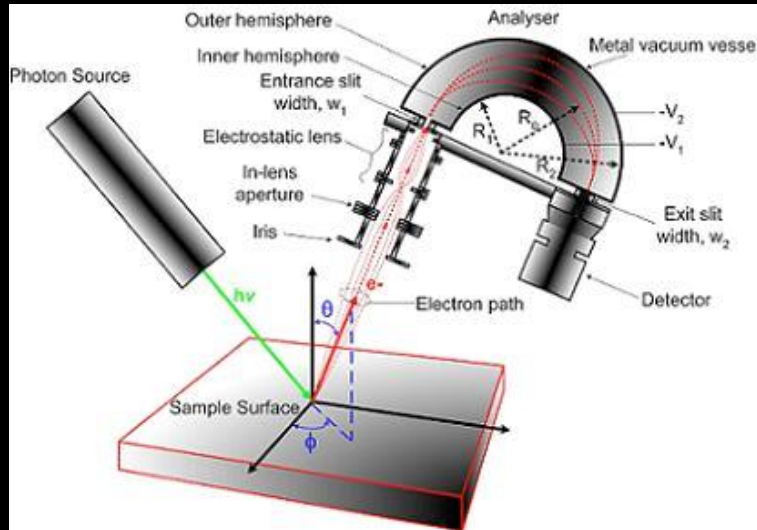


In the optimal structure, the Li-O displacement vectors are almost oriented parallel to the surface, not perpendicular as required for a traditional dipole.

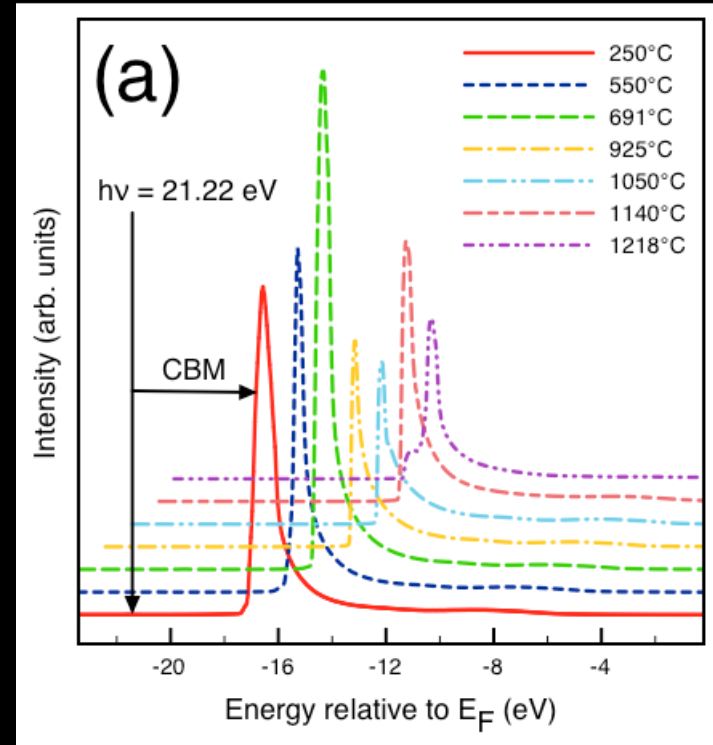


Calculated dipole is large – the NEA is more than twice that of the hydrogenated surface at -4.5 eV.

UV Photoelectron Spectroscopy of SC diamond, B-doped C(100):O,Li

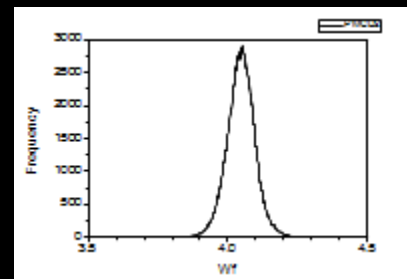
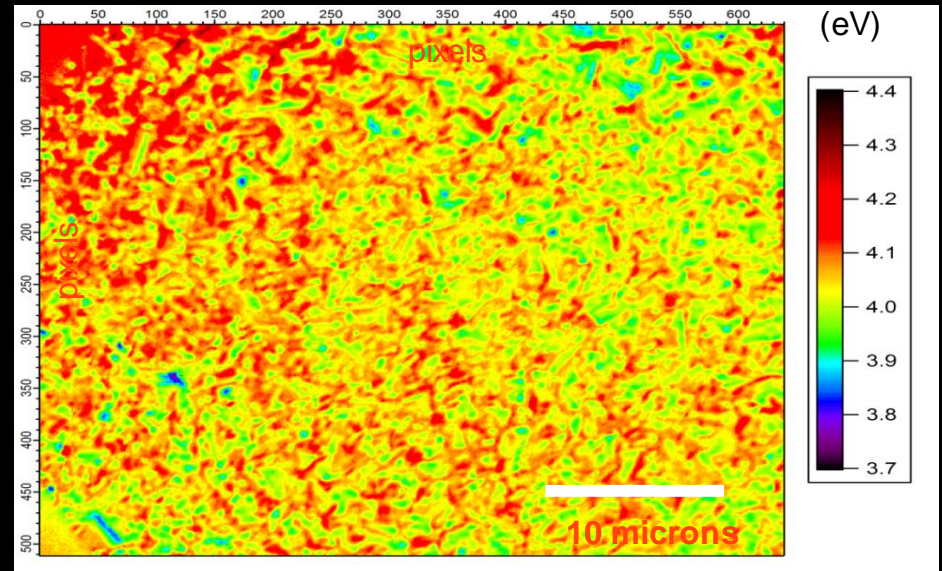


UPS: large NEA peak, remains even after annealing at 1000°C. Some breakdown is evident above 1200°C.

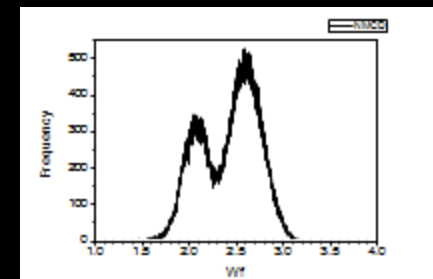


🔥 Work function of CVD Diamond films

- NanoESCA shows the average photo-electric work function of boron-doped, p-type diamond is $\sim 4.05\text{eV}$
- For nitrogen doped, n-type (1.7eV level) ranges from 2.0eV to 2.8eV
- Thermionic emission will be insignificant at temperatures accessible to solar heating (mA/cm^2 instead of A/cm^2)
- How can net flux of emission current be increased?

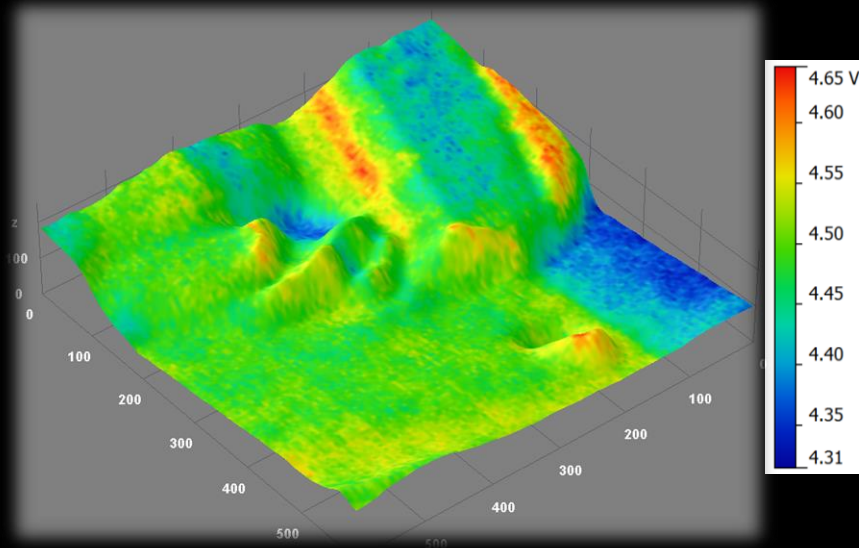


p-type



n-type

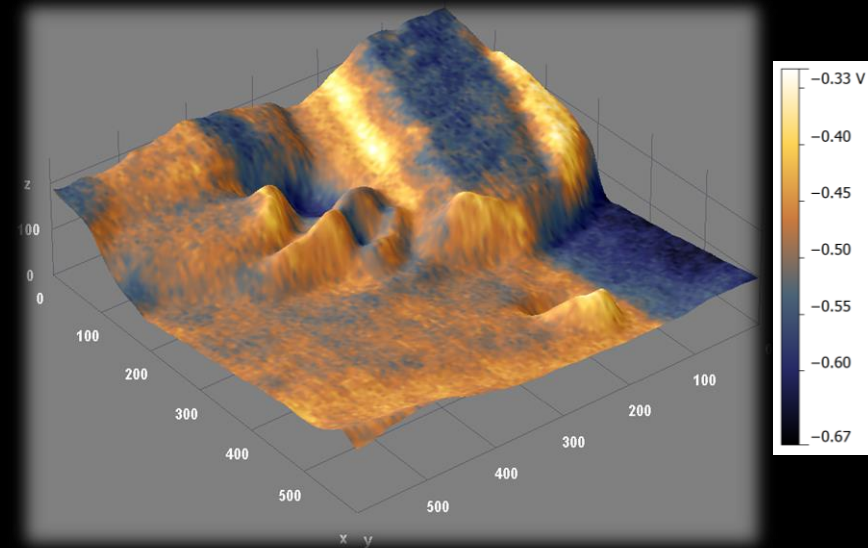
UHV Scanning Kelvin Probe Microscopy



Work function values of boron doped diamond with Li-O surface termination superimposed onto a surface plot of the same area

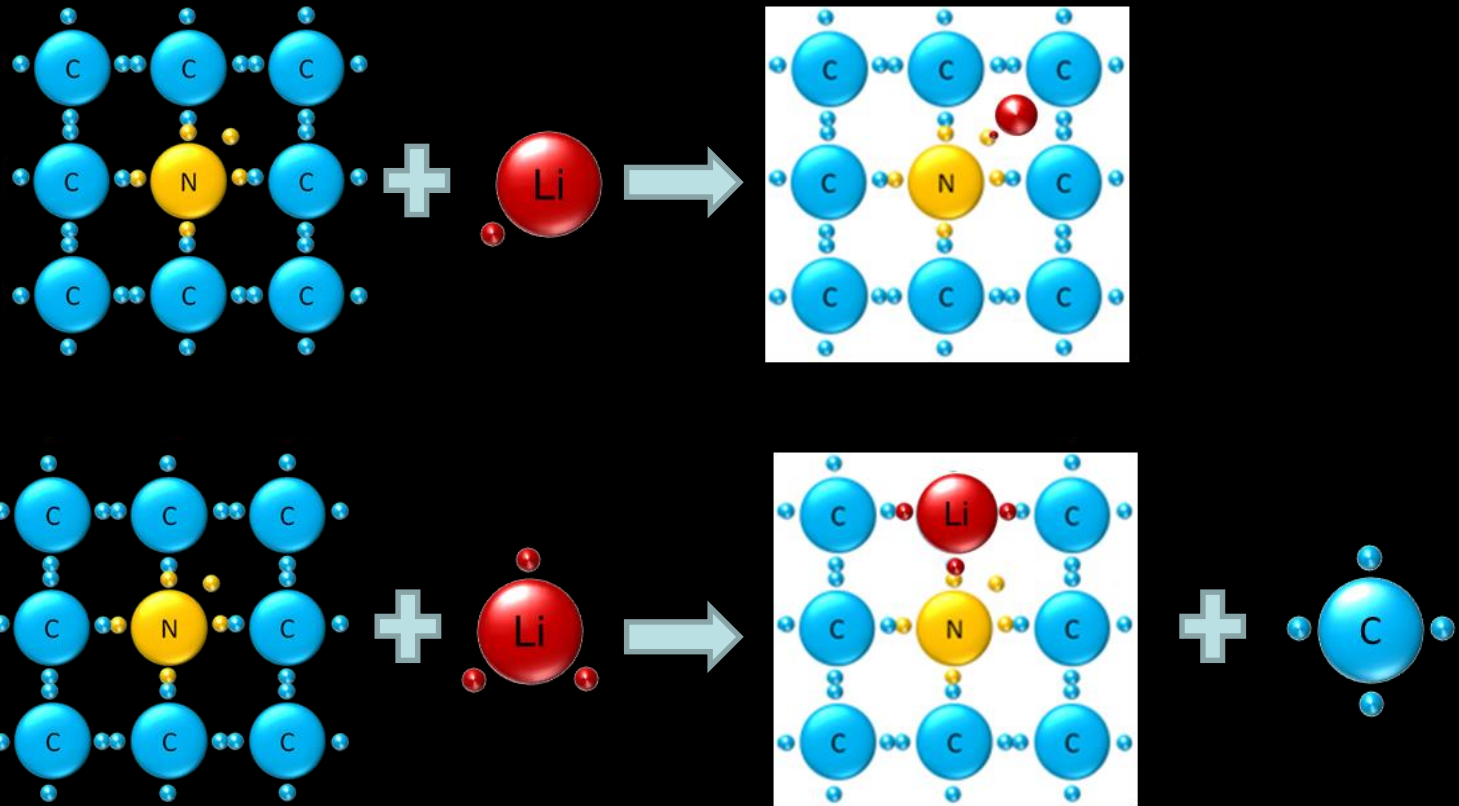
- Negative Electron Affinity: vacuum level under conduction band

- Possible to see work function differences between crystals



Negative Electron Affinity values of boron doped diamond with Li-O surface termination superimposed onto a surface plot of the same area

🔥 Modelling Co-doped Diamond

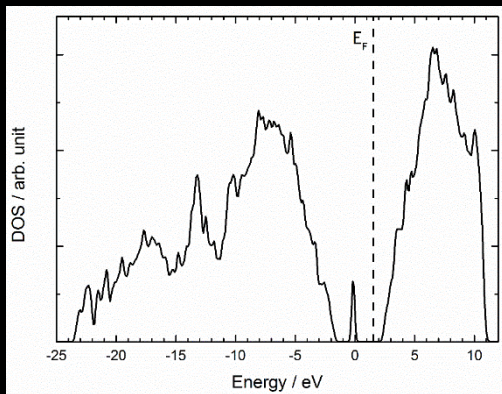
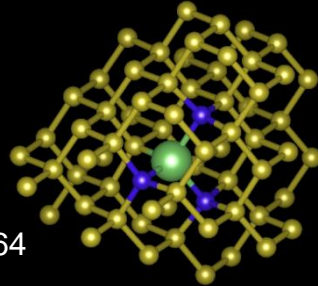


Li-N co-doped diamond films - CASTEP code simulations

Substitutional defect

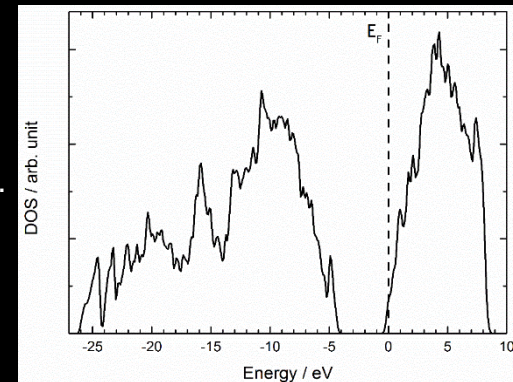
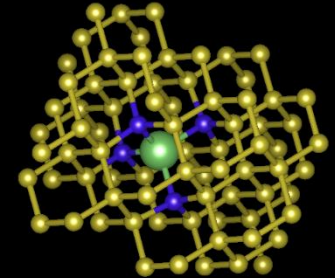
1:3 Li-to-N ratio

- Formation Energy: 3.88 eV
- Dopant concentration
 - 1.56% for Li (1 atom of Li in 64 atom supercell)
 - 4.69% for N (3 atoms of N in a 64 atom supercell)
- Fermi Level (E_F) 0.5 eV below E_c .
- Dopant level 1.90 eV below E_c .



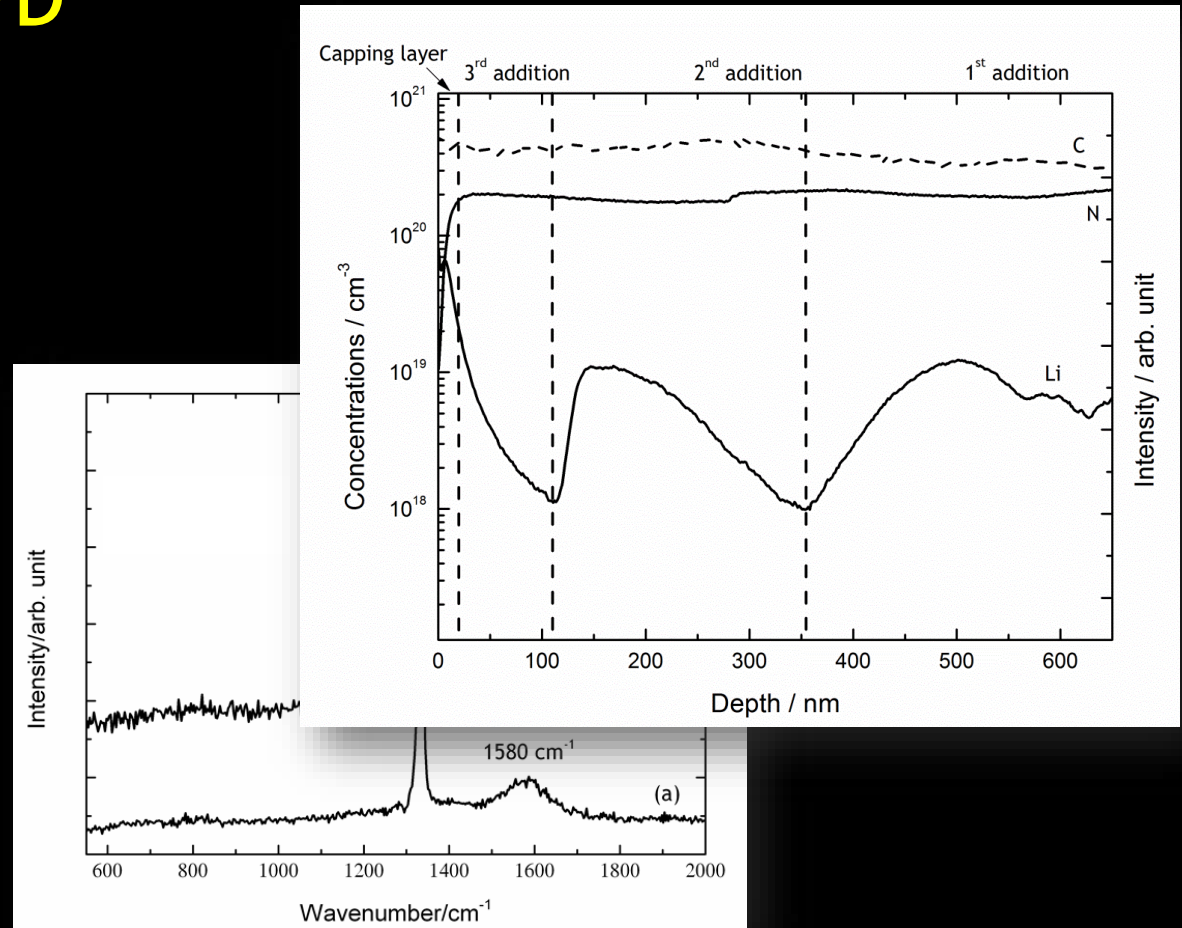
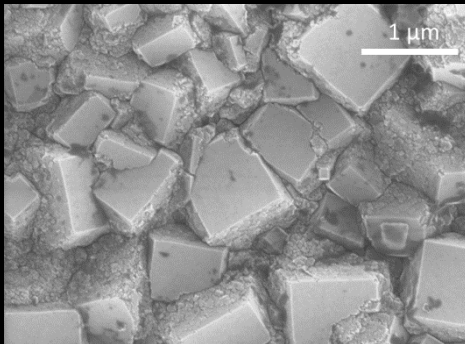
1:4 Li-to-N ratio

- Formation Energy: 4.88 eV
- Dopant concentration
 - 1.56% for Li (1 atom of Li in 64 atom supercell)
 - 6.25% for N (4 atoms of N in a 64 atom supercell)
- Fermi Level (E_F) <0.1 eV below E_c .
- Dopant level – <0.1 eV below E_c .
- The E_F and dopant energy level lying within and just below the conduction band.



Li-N co-doped diamond films - Hot Filament CVD

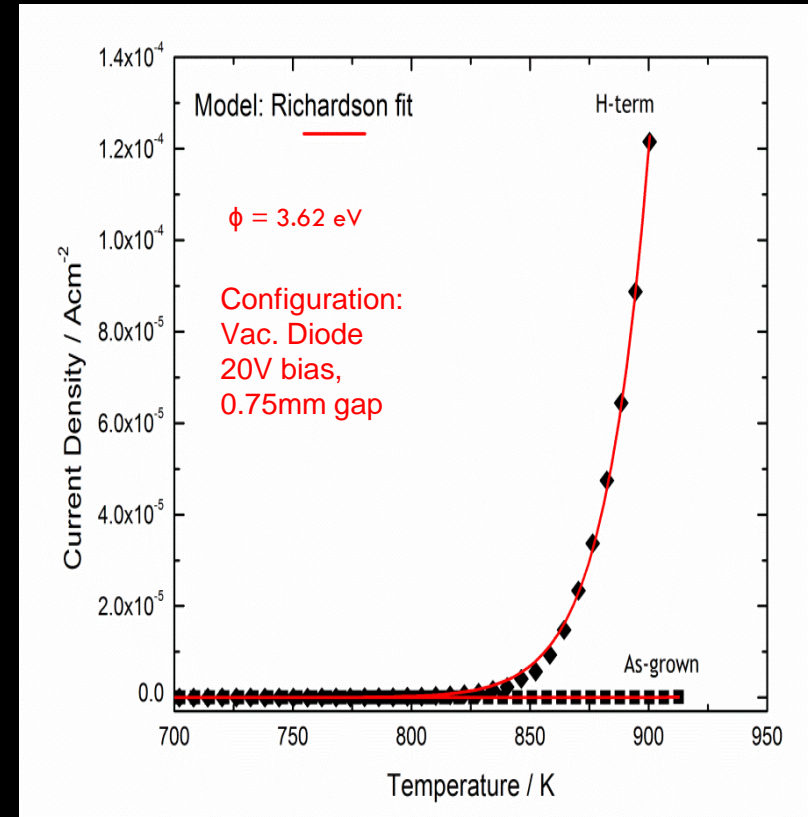
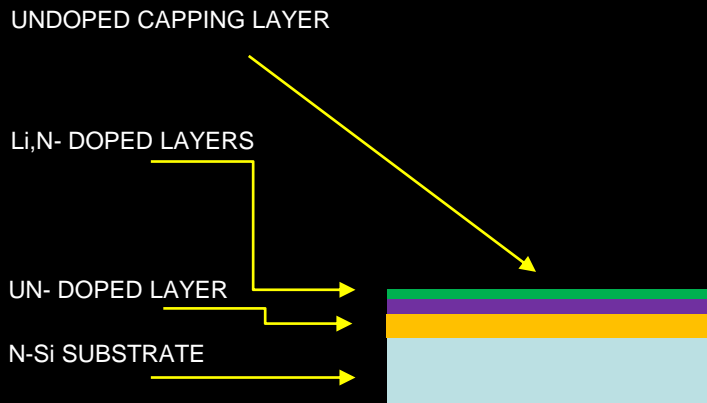
- $\sim 1.1 \times 10^{19}$ atoms of Li/cm³
- $\sim 2.1 \times 10^{20}$ atoms of N/cm³
- Li:N – 1:19
- Properties dominated by N atoms



🔥 Li-N (1:19) co-doped diamond films - Thermionic Emission

Co-doped active layer:

- Microcrystalline CVD diamond
- Hydrogen-terminated surface



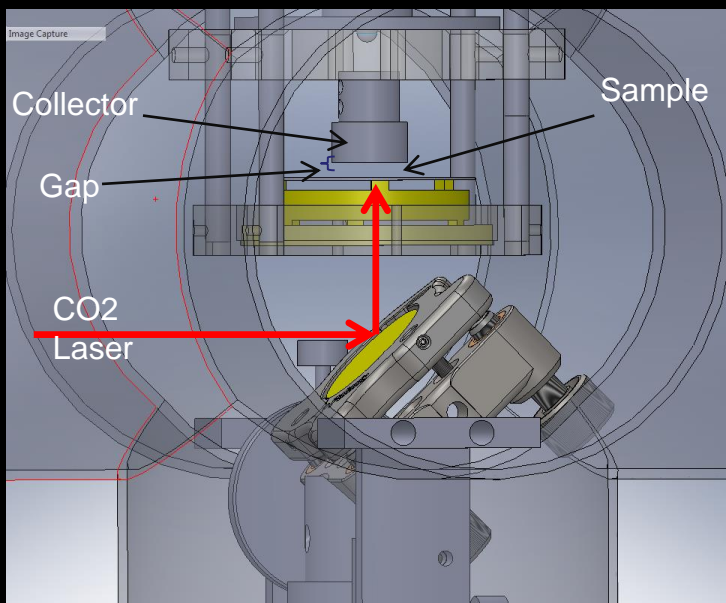
Measurements taken at ASU 2013

R. J. Nemanich, F. A.M. Koeck, Tianyin Sun,

& Z.Othman

- $T_{\text{threshold}} = 800 \text{ K}$
- $T_{\text{max}} = 900 \text{ K}$

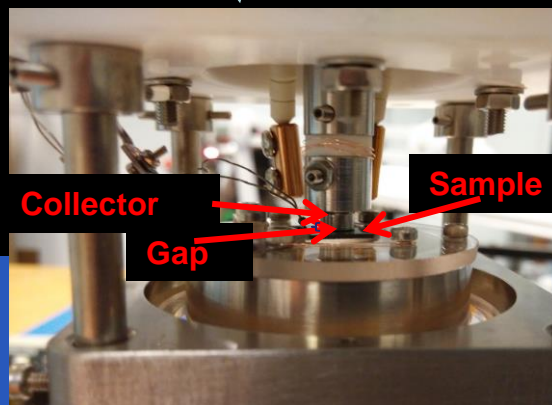
DTC Test Rigs



Laser-heated
Thermionic Set-up



NSQI- Ultra-quiet Laboratory UHV SPM
with Radiative heating



DTC Test Rigs



Electrically-heated
Thermionic Set-up

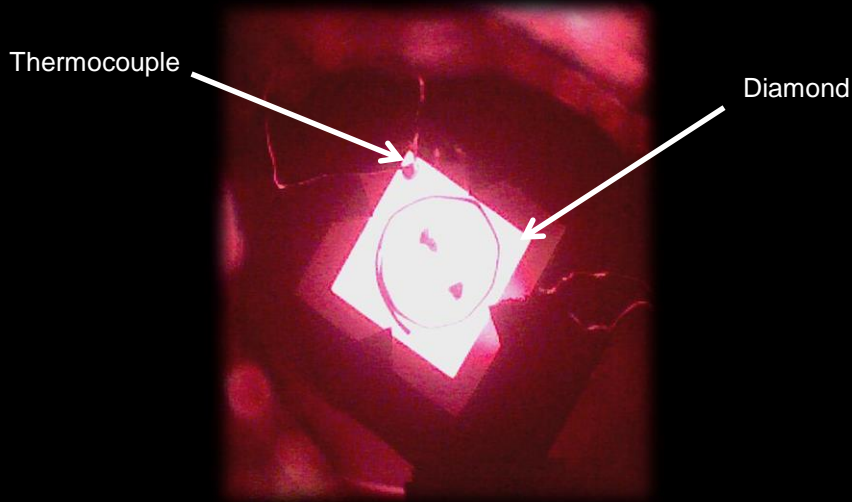


Solar
TDC Test Rig

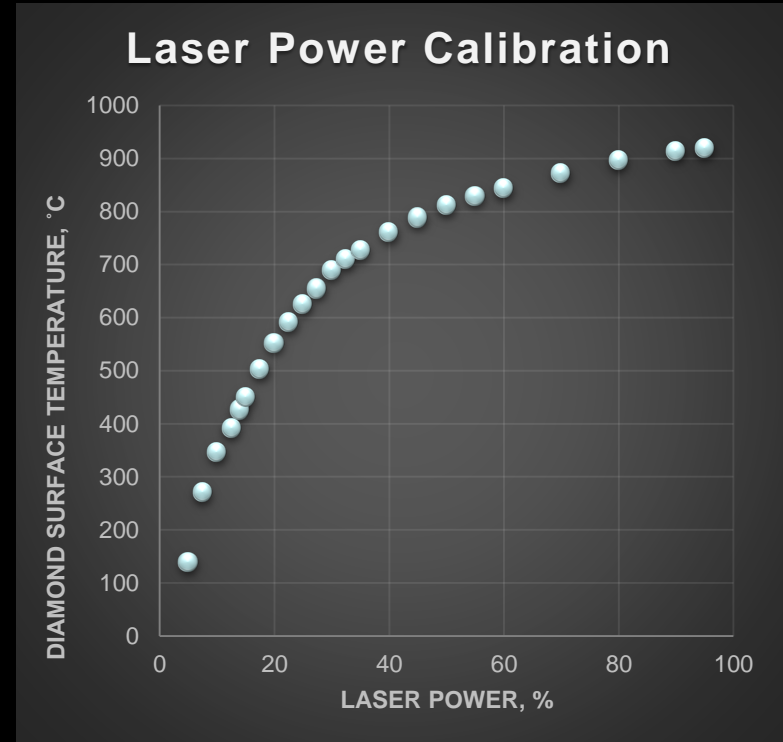
Laser-heated Temperature Calibration

Two temperature measurement methods:

- Two colour Pyrometer – High temp range
- Thermocouple : – Low temp range



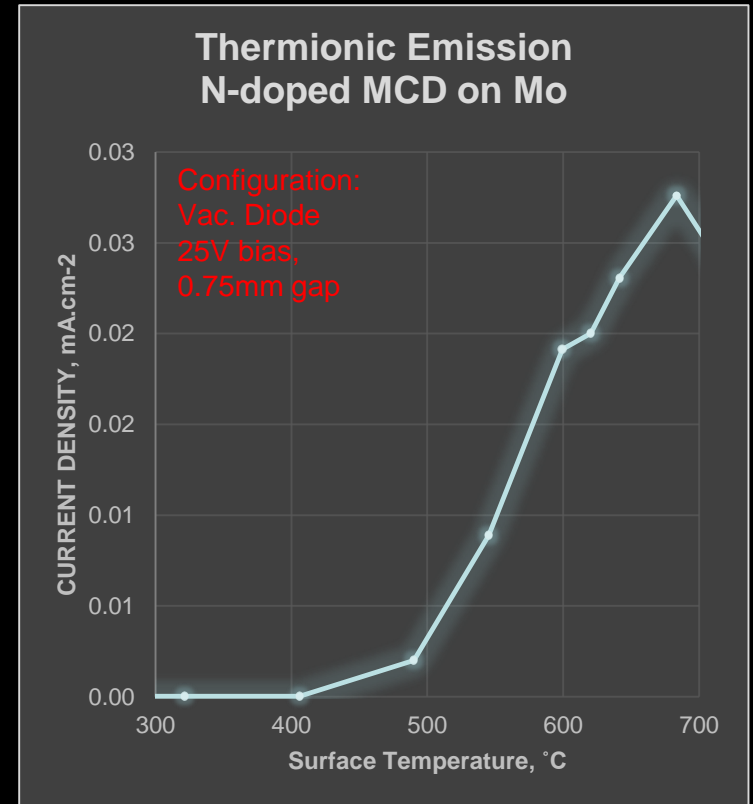
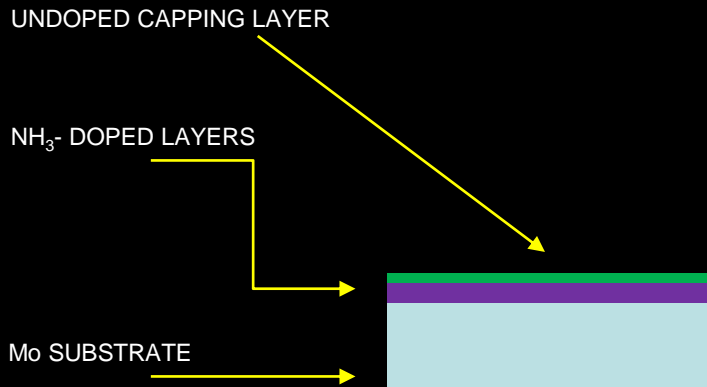
Heating test of free-standing doped diamond



Laser-heated TE - Preliminary Results

Single elemental dopant:

- Microcrystalline CVD Diamond (MCD)
- Metal Substrate
- Hydrogen-terminated surface
- N content $\sim 1 \times 10^{20}$ atoms.cm⁻³

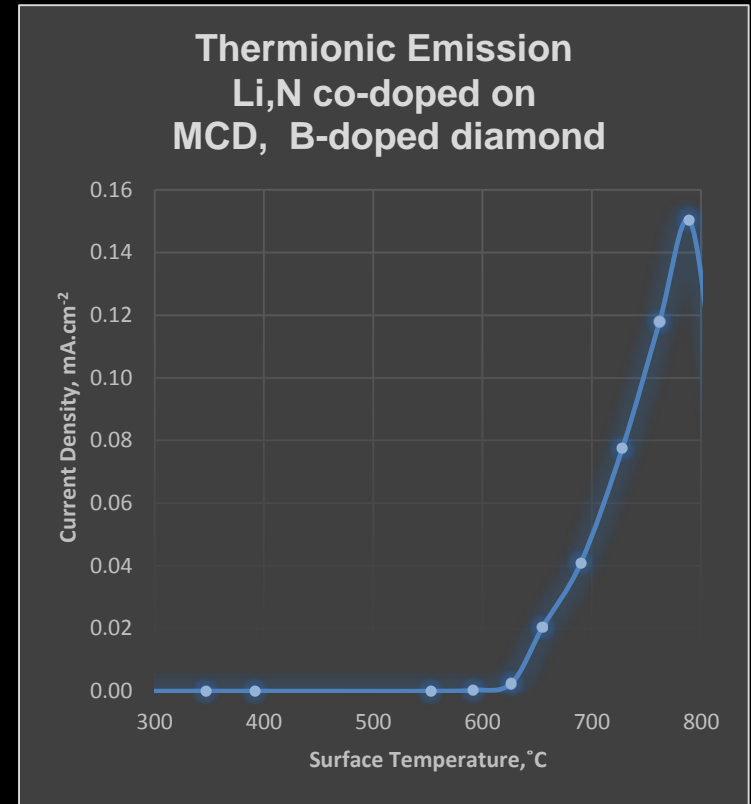
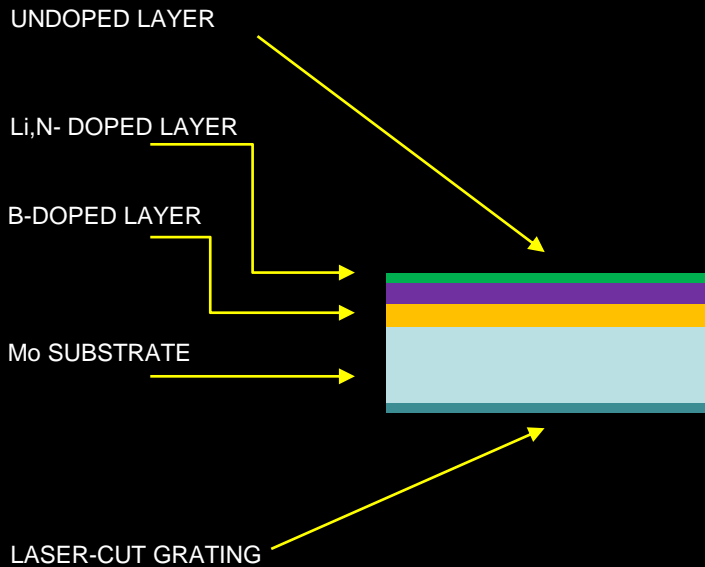


- $T_{threshold} = 673$ K
- $T_{max} = 963$ K

Laser-heated TE - Preliminary Results

Co-doped active layer:

- Metal substrate
- Hydrogen-terminated surface
- Li:B ratio TBD

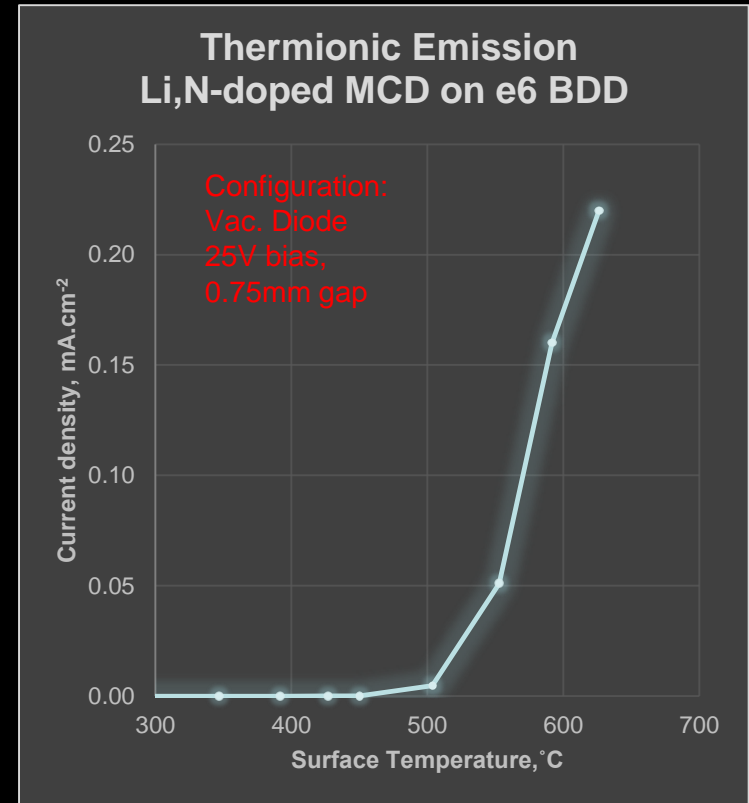
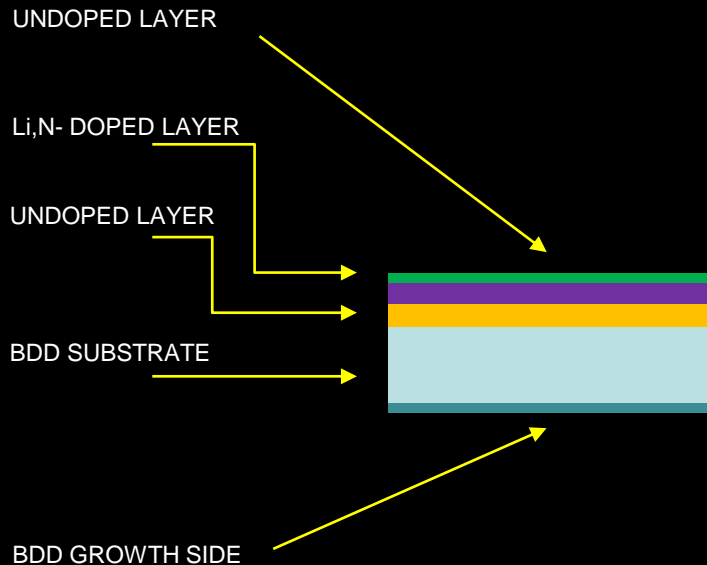


- $T_{threshold} = 903 \text{ K}$
- $T_{max} = 1063 \text{ K}$

Laser-heated TE - Preliminary Results

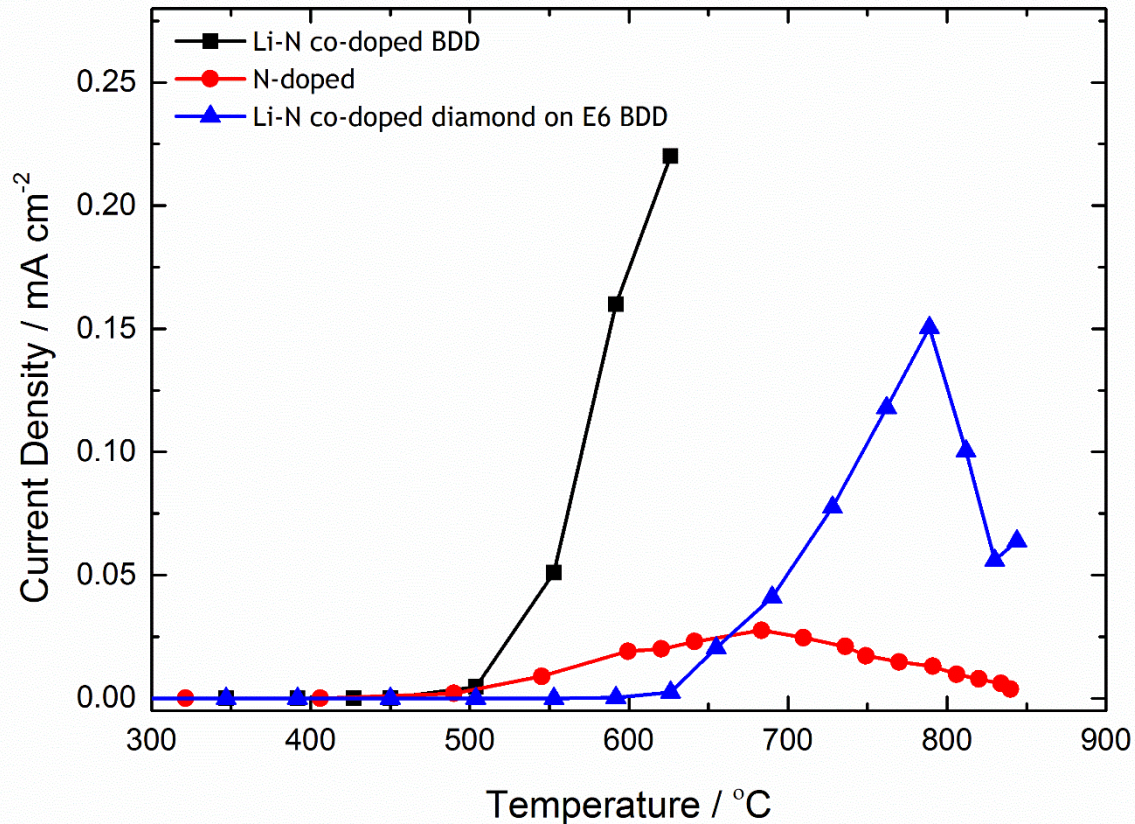
Co-doped active layer:

- Free-standing e6 BDD substrate
- Hydrogen-terminated surface
- Li:N ratio 1:19



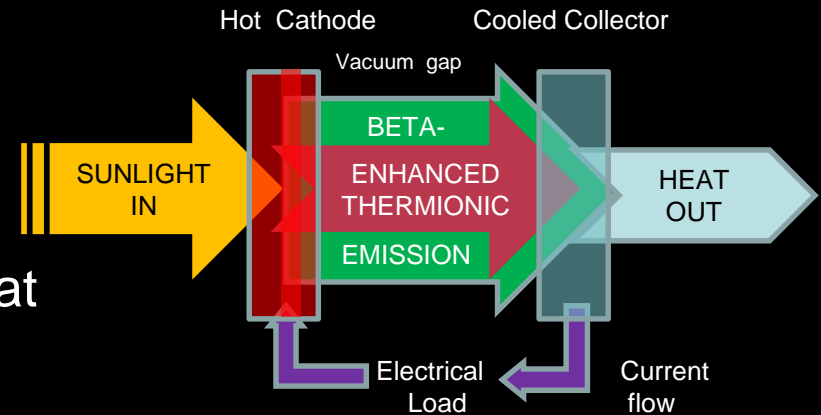
- $T_{threshold} = 723 \text{ K}$
- $T_{max} = 899 \text{ K}$

Laser-heated TE - Summary



🌿 Isotopic Diamond Converters

- Use of ^{13}C & ^{12}C diamond
 - Thermal carrier confinement
- Use of ionising ^{14}C diamond
 - Generates e-h pairs in bulk
 - Potential to generate high SEE at a diamond surface
- Potential outcomes
 - Increased flux of thermionic carriers leaving hot cathode
 - New electrode architectures



Acknowledgements

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- Co-Is:
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- Project team:
 - **S.Nunez-Sanchez**, N. Ahmad, C.Wan, J. Stokes,
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 - **Ian Bickerton**, **M.Z. Othman**, H.D. Andrade, J.Harwood, S. Halliwell, X.Zhang,
E.Pole, A.Croot, Diamond Groups, Schools of Physics and Chemistry
- ASU:
 - R. J. Nemanich, F. A.M. Koeck. Tianyin Sun
- MINATEC-LETI:
 - Olivier Renault

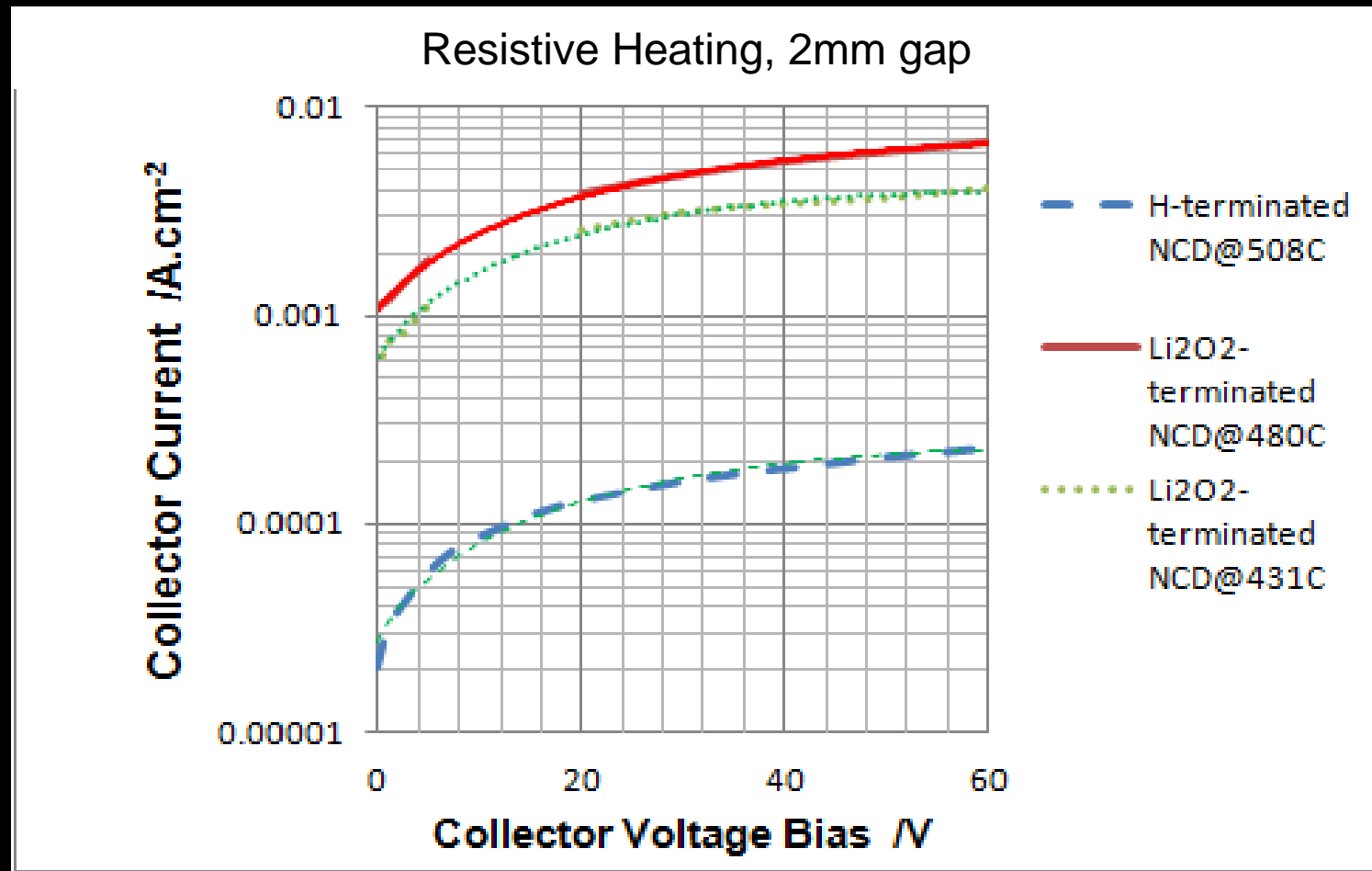




University of
BRISTOL



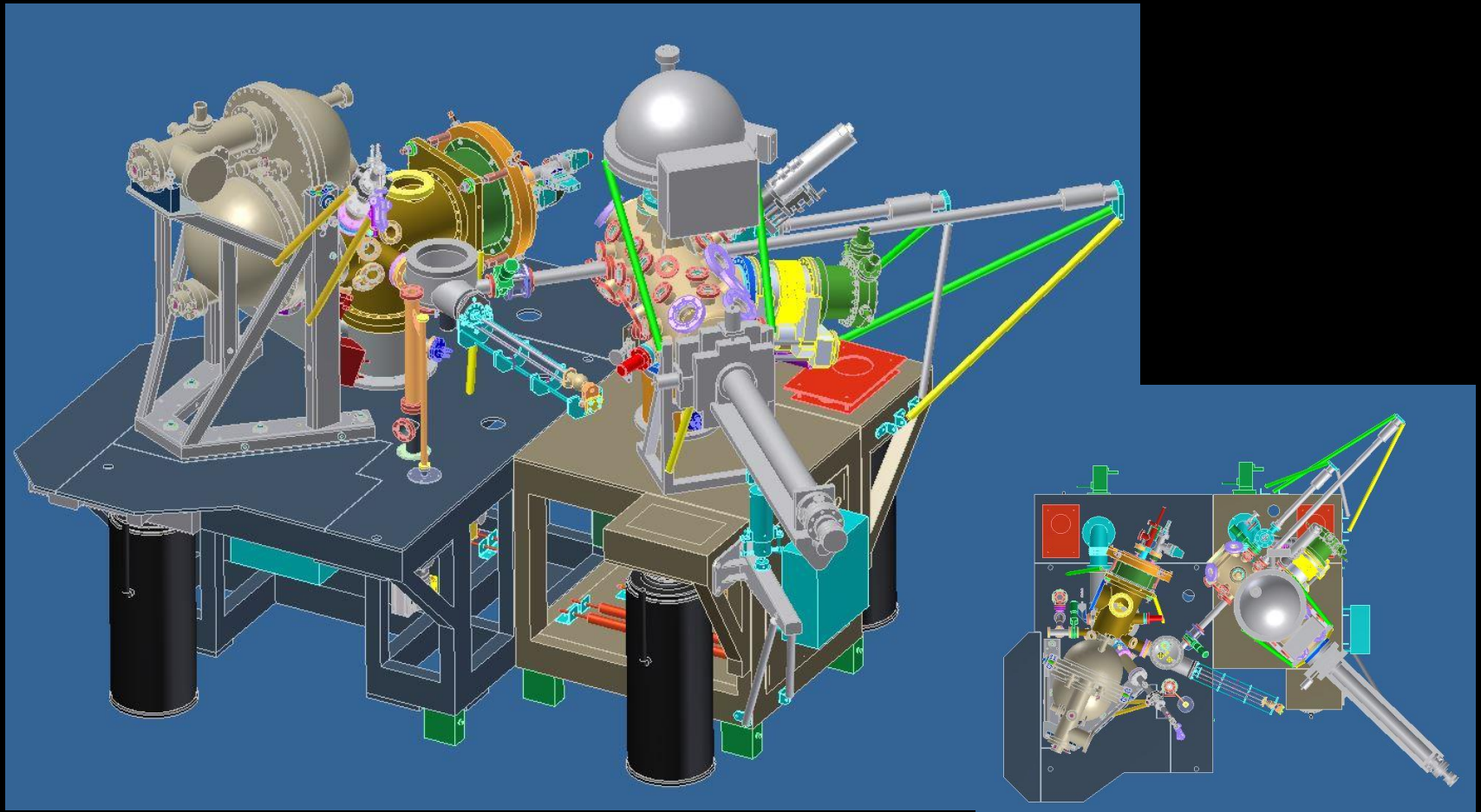
Li-N co-doped diamond films + O, Li termination - Thermionic Emission





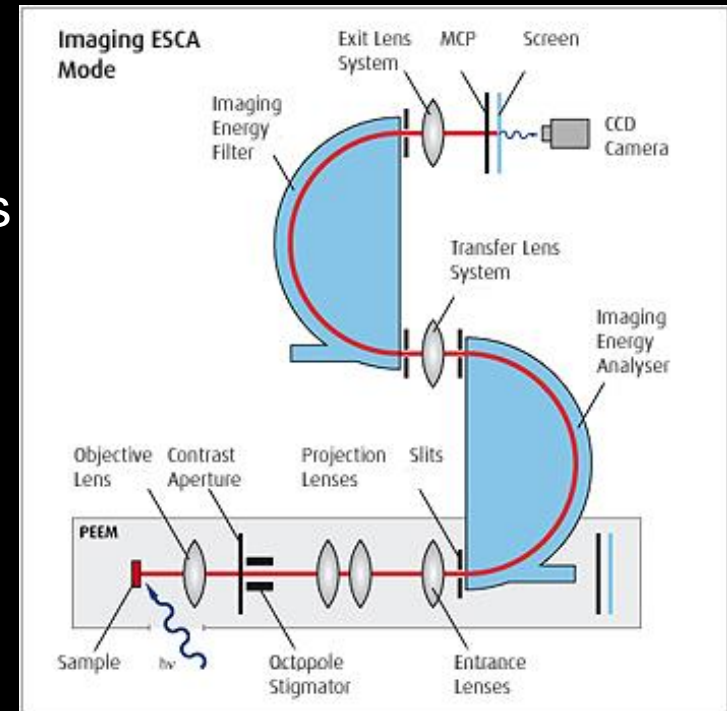
NanoESCA

Mk II system configuration for Bristol



NanoESCA Laboratory Specification

- Focussed Light sources
 - Energy Resolution in PEEM modes
 - VUV : 50 (28) meV
 - X-ray : 190 (100) meV
 - Lateral edge resolution in PEEM
 - VUV: 60 (20) nm
 - X-ray : 480 (320) nm
- Switchable between real space and k-space modes by control of transfer lens (k space resolution 10\AA^{-1})

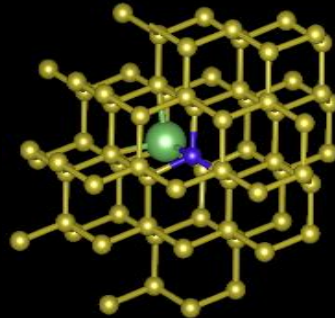


🔥 Li-N co-doped diamond films - CASTEP code simulations

Interstitial defect

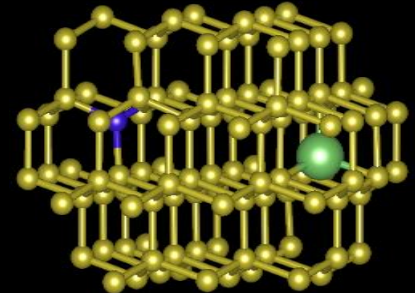
1:1 Li-to-N ratio (next to each other)

- Formation Energy – 9.41 eV
- Dopant concentration
 - 1.56% for Li (1 atom of Li in 64 atoms supercell)
 - 1.56% for N (1 atom of N in 64 atoms supercell)



1:1 Li-to-N ratio (far apart)

- Formation Energy – 11.32 eV
- Dopant concentration
 - 1.56% for Li (1 atom of Li in 64 atoms supercell)
 - 1.56% for N (1 atom of N in 64 atoms supercell)



- From the formation energy calculated. N atom act as a trap to pin down Li atom and this reduced the mobility of Li in diamond at high temperature.
- This concept is suitable to immobilise Li in diamond lattice.

